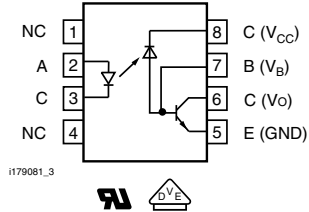


## High Speed Optocoupler, 1 MBd, Transistor Output



I179075



### FEATURES

- Isolation test voltage 5300 V<sub>RMS</sub>
- TTL compatible
- High bit rates: 1 MBit/s
- High common mode interference immunity
- Bandwidth 2 MHz
- Open collector output
- External base wiring possible
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


**RoHS**  
COMPLIANT

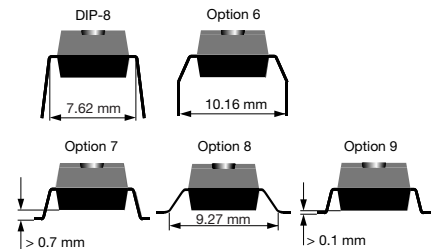
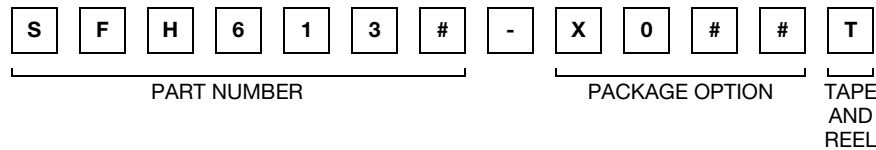
### DESCRIPTION

The SFH6135 and SFH6136 optocouplers feature a high signal transmission rate and a high isolation resistance. They have a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector which consists of a photo diode and a high-speed transistor in a DIP-8 plastic package. Signals can be transmitted between two electrically separated circuits up to frequencies of 2 MHz. The potential difference between the circuits to be coupled should not exceed the maximum permissible reference voltages.

### AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- DIN EN 60747-5-5 (VDE 0884)

### ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)	
<b>UL</b>	<b>≥ 7</b>	<b>≥ 19</b>
DIP-8	SFH6135	SFH6136
DIP-8, 400 mil, option 6	SFH6135-X006	SFH6136-X006
SMD-8, option 7	SFH6135-X007T <sup>(1)</sup>	SFH6136-X007
SMD-8, option 9	-	SFH6136-X009T
<b>VDE, UL</b>	<b>≥ 7</b>	<b>≥ 19</b>
DIP-8	SFH6135-X001	SFH6136-X001
DIP-8, 400 mil, option 6	-	SFH6136-X016
SMD-8, option 7	-	SFH6136-X017T <sup>(1)</sup>
SMD-8, option 8	-	SFH6136-X018
SMD-8, option 9	SFH6135-X019	SFH6136-X019T <sup>(1)</sup>

#### Note

<sup>(1)</sup> Also available in tubes; do not add T to end

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		$V_R$	3	V
Forward current		$I_F$	25	mA
Peak forward current	$t = 1\text{ ms}$ , duty cycle 50 %	$I_{FM}$	50	mA
Maximum surge forward current	$t \leq 1\text{ }\mu\text{s}$ , 300 pulses/s	$I_{FSM}$	1	A
Thermal resistance		$R_{thja}$	700	K/W
Power dissipation		$P_{diss}$	45	mW
<b>OUTPUT</b>				
Supply voltage		$V_S$	- 0.5 to 30	V
Output voltage		$V_O$	- 0.5 to 25	V
Emitter base voltage		$V_{EBO}$	5	V
Output current		$I_O$	8	mA
Maximum output current		$I_O$	16	mA
Base current		$I_B$	5	mA
Thermal resistance		$R_{thja}$	300	K/W
Power dissipation	$T_{amb} = 70\text{ }^{\circ}\text{C}$	$P_{diss}$	100	mW
<b>COUPLER</b>				
Isolation test voltage		$V_{ISO}$	5300	$V_{RMS}$
Pollution degree (DIN VDE 0110)			2	
Isolation resistance	$V_{IO} = 500\text{ V}$ , $T_{amb} = 25\text{ }^{\circ}\text{C}$	$R_{IO}$	$\geq 10^{12}$	$\Omega$
	$V_{IO} = 500\text{ V}$ , $T_{amb} = 100\text{ }^{\circ}\text{C}$	$R_{IO}$	$\geq 10^{11}$	$\Omega$
Storage temperature range		$T_{stg}$	- 55 to + 125	$^{\circ}\text{C}$
Ambient temperature range		$T_{amb}$	- 55 to + 100	$^{\circ}\text{C}$
Soldering temperature <sup>(1)</sup>	max. $\leq 10\text{ s}$ , dip soldering $\geq 0.5\text{ mm}$ distance from case bottom	$T_{sld}$	260	$^{\circ}\text{C}$

### Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to wave profile for soldering conditions for through hole devices .

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>							
Forward voltage	$I_F = 16\text{ mA}$		$V_F$		1.6	1.9	V
Breakdown voltage	$I_R = 10\text{ }\mu\text{A}$		$V_{BR}$	3			V
Reverse current	$V_R = 3\text{ V}$		$I_R$		0.5	10	$\mu\text{A}$
Capacitance	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$		$C_O$		125		pF
Temperature coefficient of forward voltage	$I_F = 16\text{ mA}$		$\Delta V_F / \Delta T_{amb}$		1.7		mV/ $^{\circ}\text{C}$
<b>OUTPUT</b>							
Logic low supply current	$I_F = 16\text{ mA}$ , $V_O = \text{open}$ , $V_{CC} = 15\text{ V}$		$I_{CCL}$		150		$\mu\text{A}$
Logic high supply current	$I_F = 0\text{ V}$ , $V_O = \text{open}$ , $V_{CC} = 15\text{ V}$		$I_{CCH}$		0.01	1	$\mu\text{A}$
Output voltage, output low	$I_F = 16\text{ mA}$ , $V_{CC} = 4.5\text{ V}$ , $I_O = 1.1\text{ mA}$	SFH6135	$V_{OL}$		0.1	0.4	V
	$I_F = 16\text{ mA}$ , $V_{CC} = 4.5\text{ V}$ , $I_O = 2.4\text{ mA}$	SFH6136	$V_{OL}$		0.1	0.4	V
Output current, output high	$I_F = 0\text{ mA}$ , $V_O = V_{CC} = 5.5\text{ V}$		$I_{OH}$		3	500	nA
	$I_F = 0\text{ mA}$ , $V_O = V_{CC} = 15\text{ V}$		$I_{OH}$		0.01	1	$\mu\text{A}$

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>COUPLER</b>							
Capacitance (input to output)	$f = 1\text{ MHz}$		$C_{IO}$		0.6		pF

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

<b>CURRENT TRANSFER RATIO</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_F = 16\text{ mA}$ , $V_O = 0.4\text{ V}$ , $V_{CC} = 4.5\text{ V}$	SFH6135	CTR	7	16		%
		SFH6136	CTR	19	35		%
	$I_F = 16\text{ mA}$ , $V_O = 0.5\text{ V}$ , $V_{CC} = 4.5\text{ V}$	SFH6135	CTR	5			%
		SFH6136	CTR	15			%



Fig. 1 - Schematics

<b>SWITCHING CHARACTERISTICS</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
High to low	$I_F = 16\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 4.1\text{ k}\Omega$	SFH6135	$t_{PHL}$		0.3	1.5	$\mu\text{s}$
	$I_F = 16\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1.9\text{ k}\Omega$	SFH6136	$t_{PHL}$		0.2	0.8	$\mu\text{s}$
Low to high	$I_F = 16\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 4.1\text{ k}\Omega$	SFH6135	$t_{PLH}$		0.3	1.5	$\mu\text{s}$
	$I_F = 16\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1.9\text{ k}\Omega$	SFH6136	$t_{PLH}$		0.2	0.8	$\mu\text{s}$



Fig. 2 - Common Mode Interference Immunity

COMMON MODE TRANSIENT IMMUNITY							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
High	$V_{CM} = 10 V_{P-P}, V_{CC} = 5 V,$ $I_F = 0 mA, R_L = 4.1 k\Omega$	SFH6135	CM <sub>H</sub>		1000		V/ $\mu$ s
	$V_{CM} = 10 V_{P-P}, V_{CC} = 5 V,$ $I_F = 0 mA, R_L = 1.9 k\Omega$	SFH6136	CM <sub>H</sub>		1000		V/ $\mu$ s
Low	$V_{CM} = 10 V_{P-P}, V_{CC} = 5 V,$ $I_F = 0 mA, R_L = 4.1 k\Omega$	SFH6135	CM <sub>L</sub>		1000		V/ $\mu$ s
	$V_{CM} = 10 V_{P-P}, V_{CC} = 5 V,$ $I_F = 0 mA, R_L = 1.9 k\Omega$	SFH6136	CM <sub>L</sub>		1000		V/ $\mu$ s

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
V <sub>IOTM</sub>			8000				V
V <sub>IORM</sub>			890				V
P <sub>SO</sub>					500		mW
I <sub>SI</sub>					300		mA
T <sub>SI</sub>					175		°C
Creepage distance	Standard DIP-8		7				mm
Clearance distance	Standard DIP-8		7				mm
Creepage distance	400 mil DIP-8		8				mm
Clearance distance	400 mil DIP-8		8				mm

**Note**

- As per IEC 60747-5-5, §7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

**TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)



Fig. 3 - LED Forward Current vs. Forward Voltage



Fig. 4 - Permissible Forward LED Current vs. Temperature



Fig. 5 - Permissible Power Dissipation vs. Temperature



Fig. 8 - Propagation Delay vs. Ambient Temperature - SFH6136



Fig. 6 - Output Current vs. Output Voltage



Fig. 9 - Propagation Delay vs. Ambient Temperature - SFH6135



Fig. 7 - Output Current vs. Temperature

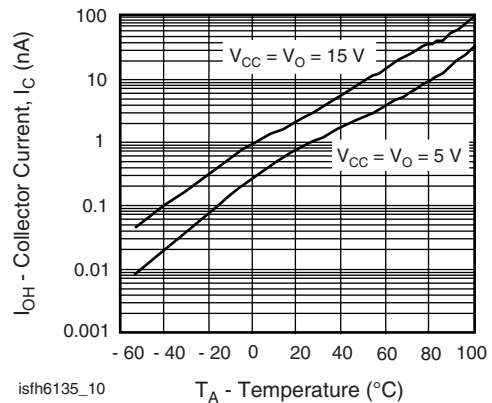


Fig. 10 - Logic High Output Current vs. Temperature

# SFH6135, SFH6136



Vishay Semiconductors High Speed Optocoupler, 1 MBd,  
Transistor Output



Fig. 11 - Small Signal Current Transfer Ratio vs. Quiescent Input Current

## PACKAGE DIMENSIONS in millimeters



i178006



# SFH6135, SFH6136

High Speed Optocoupler, 1 MBd, Transistor Output  
Vishay Semiconductors

Option 6



Option 7



Option 8



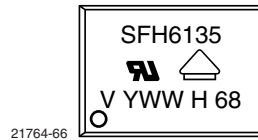
Option 9



20802-1



## PACKAGE MARKING





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